

# SF1G1 THRU SF1G7

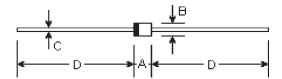
## **GLASS PASSIVATED SUPER FAST RECTIFIER**

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere

#### **Features**

- Superfast recovery times
- Low forward voltage, high current capability
- Hermetically sealed
- Low leakage
- High surge capability
- Plastic package has Underwriters Laboratories
   Flammability Classification 94V-0 utilizing
   Flame retardant epoxy molding compound

<u>R-1</u>



#### **Mechanical Data**

• Case: Molded plastic, R-1

 Terminals: Axial leads, solderable to MIL-STD-202, method 208

• Polarity: Color band denotes cathode end

Mounting Position: Any

• Weight: 0.007 ounce, 0.205 gram

DIMENSIONS										
DIM	inches		m	Note						
	Min.	Max.	Min.	Max.	Note					
Α	0.114	0.138	2.9	3.5						
В	0.095	0.099	2.42	2.51	ф					
С	0.020	0.024	0.5	0.6	ф					
D	1.000	-	25.40	-						

# **Maximum Ratings and Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified. Resistive or inductive load, 60Hz.

	Symbols	SF 1G1	SF 1G2	SF 1G3	SF 1G4	SF 1G5	SF 1G6	SF 1G7	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
$\begin{array}{c} \text{Maximum average forward current} \\ \text{0.375" (9.5mm) lead length at } T_{\text{A}} = 55^{\circ}\text{C} \end{array} \qquad \qquad \text{I}_{\text{(AV)}}$			1.0	1.0					
Peak forward surge current, I <sub>FM</sub> (surge): 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method)	rd surge current, I <sub>M</sub> (surge): e half sine-wave superimposed I <sub>FSM</sub> 30.0 id (MIL-STD-750D 4066 method)					Amps			
Maximum forward voltage at 1.0 ADC	V <sub>F</sub>	0.95 1.27 1.75					Volts		
Maximum DC reverse current at rated DC blocking voltage	I <sub>R</sub>	5.0							μА
Maximum DC reverse current at rated DC blocking voltage $T_A$ =125 $^{\circ}C$	I <sub>R</sub>	400.0							μА
Maximum reverse recovery time (Note 1)	T <sub>rr</sub>	35.0							nS
Typical junction capacitance (Note 2)	C <sub>J</sub>	63.0							ρF
Operating and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150							°C

#### Notes:

- (1) Reverse recovery test conditions:  $I_{E}=0.5A$ ,  $I_{R}=1.0A$ ,  $I_{R}=0.25A$
- (2) Measured at 1.0MHz and applied reverse voltage of 4.0 VDC

### RATINGS AND CHARACTERISTIC CURVES

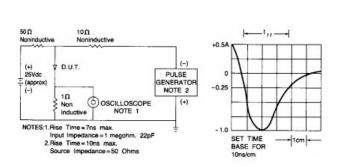


Fig. 1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

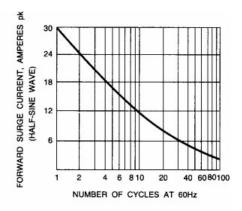


Fig. 2 – MAXIMUM NON-REPEITIVE SURGE CURRENT

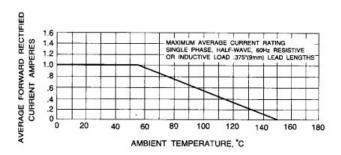


Fig. 3 - MAXIMUM AVERAGE FORWARD CURRENT RATING

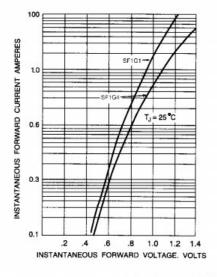


Fig. 4-TYPICAL JUNCTION CAPACITANCE

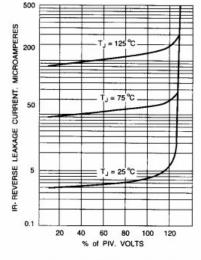


Fig. 5-TYPICAL REVERSE CHARACTERISTICS

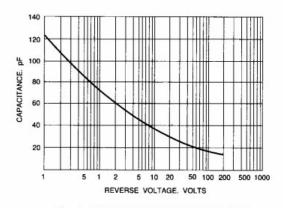


Fig. 6 - TYPICAL JUNCTION CAPACITANCE